

Instructions for Preparing Camera-Ready Manuscripts for International Symposium on Compound Semiconductors (Bold, 12 point, Times or Times New Roman)

First Author^a, Second Author^b, Third Author^{c,*}

(10point, Times or Times New Roman, Name of the presenting author is underlined.)

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(Italic, 10point, Times or Times New Roman)

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This leaf presents instructions for preparing abstract for iscs2007 symposium. Camera-ready abstracts of the accepted papers will be printed in the same size with the originals and bound in the Technical Digest delivered at the conference site. The set of instructions is given in the style and format to be used by the authors.

Abstract should contain a concise description of the objectives of the study, method of approach, significant results and conclusions. Submitted abstracts must be camera-ready. Use A4-size or US-letter size. For A4-size, set all margins to 25mm. If you use US letter size, set all margins to 1 inch. Pages will be reproduced in the same size on A4-size papers in the symposium Technical Digest.

Text must be printed clearly in English. The title should be placed at the top, followed by the author(s) name(s), affiliation(s) and address(es), and email address of the contact person if available. Use capital letters for the initial letter of each word except articles, prepositions and conjunctions. Place a blank line between the title and author name(s), and between address(es) and the main text. The main text should be typed by using 10 point Times (or Times New Roman) font with 14-pt line spacing. References should be placed at the end of the main text with a blank line before the reference. The page length must be **one page including figures and tables**. A paper may be finished with Figures and Tables. If your manuscript includes digital photographs, the resolution should be at least 150dpi. Figure captions should be placed below the figures; table captions above the tables. Arabic numbers should be used for the figures like Fig.1, and Roman numbers for tables like Table I. Place a blank line between the text and the tables or figures. Use proportional serif fonts such as “Times New Roman”, “Dutch Roman” or “Roman”. Font style is 12pt bold for the title, 10pt italic for affiliations and addresses, and 10pt normal for others. List and number all the references at the end of the paper as below. The reference number should be designed like [1], [2,3] and [4,7-9] when referring to them in the text.

We wish to thank all the authors of the iscs2007 abstracts. We use instruction manual originally described by Prof. Ishida (Toyohashi Univ. Technology) and Prof. Amano (Meijo Univ.) after some modifications.

[1] A. Bcde, F. Ghijk, L. Mnop, Q. Rstu and V. Wxyz: Appl. Phys. Lett. 71 (1997) 2067.

[2] Z. Yxwv, U.Tsrq, P. Onml, K. Jihg and E. Dcba: Inst. Phys. Conf. Ser. No. 145 (1996) 925.

[3] H. C. Casy, Jr. and M. B. Panish: Heterostructure Lasers (Academic Press, New York, 1978), Part B, p.71.

Table I. Scope and topic of ISCS2007.

No.	Subcommittee
1.	Growth and nanostructure formation
2.	Transport devices
3.	Photonic devices
4.	Physics
5.	Spintronics
6.	Characterization, nanoprobe and nanomechanics
7.	GaN and related semiconductors
8.	Oxide semiconductors
9.	SiGe and related materials
10.	Carbon related materials
11.	Organic semiconductor and other soft materials



Fig. 1. Kyoto University Clock Tower where ISCS2007 will be held. This is color example. However, please remind that all figures and photographs are printed in grey scale in the abstract.